

Is Now Part of

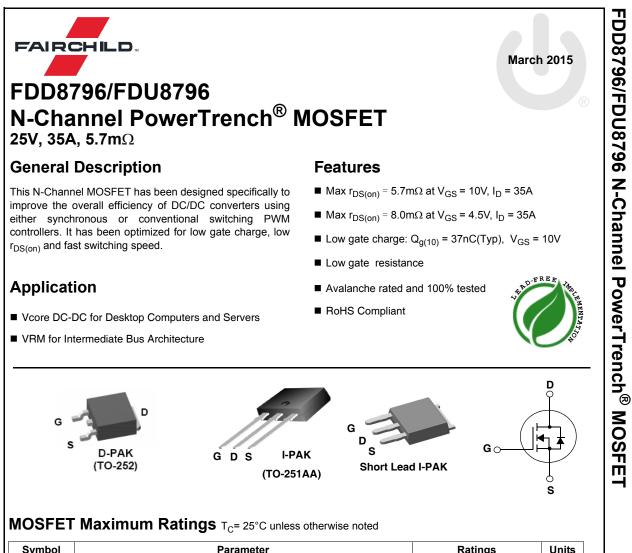


## **ON Semiconductor**®

# To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (\_), the underscore (\_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (\_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at <a href="mailto:www.onsemi.com">www.onsemi.com</a>. Please email any questions regarding the system integration to <a href="mailto:Fairchild\_questions@onsemi.com">Fairchild\_questions@onsemi.com</a>.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or unavteries, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out or i, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor and is officers, employees, uniotificated use, even if such claim any manner.



Symbol	Parameter		Ratings	Units	
V <sub>DS</sub>	Drain to Source Voltage		25	V	
V <sub>GS</sub>	Gate to Source Voltage		±20	V	
ID	Drain Current -Continuous (Package Limited) -Continuous (Die Limited)		35		
			98	Α	
	-Pulsed (N	ote 1)	305		
E <sub>AS</sub>	Single Pulse Avalanche Energy (N	ote 2)	91	mJ	
PD	Power Dissipation		88	W	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature		-55 to 175	°C	
Fhermal	Characteristics				
$R_{\theta JC}$	Thermal Resistance, Junction to Case TO_252, TO_251		1.7	°C/W	

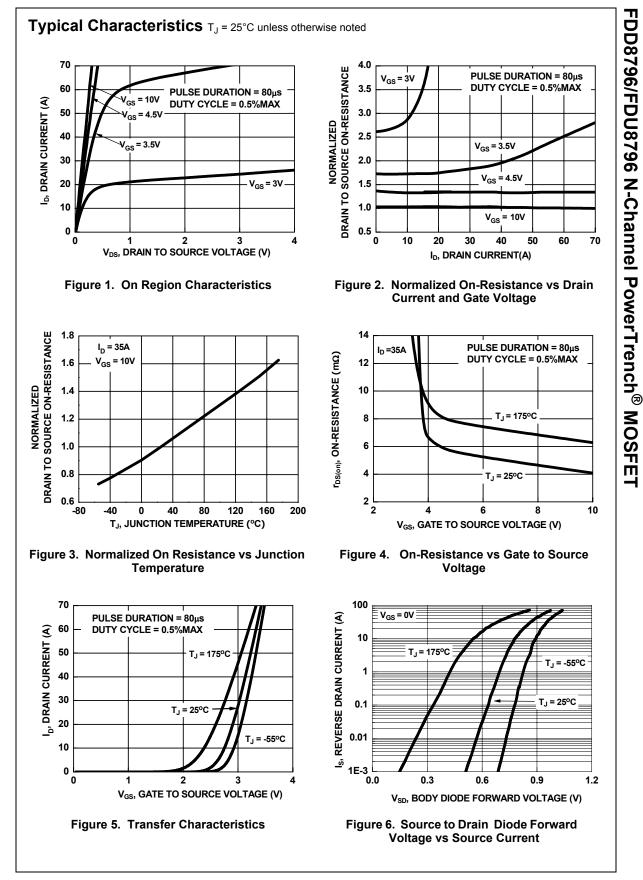
$R_{\thetaJC}$	Thermal Resistance, Junction to Case TO_252, TO_251	1.7	°C/W
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient TO_252, TO_251	100	°C/W
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient TO-252,1in <sup>2</sup> copper pad area	52	°C/W

## Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD8796	FDD8796	TO-252AA	13"	16mm	2500 units
FDU8796	FDU8796	TO-251AA	N/A (Tube)	N/A	75 units
FDU8796	FDU8796_F071	TO-251AA	N/A (Tube)	N/A	75 units

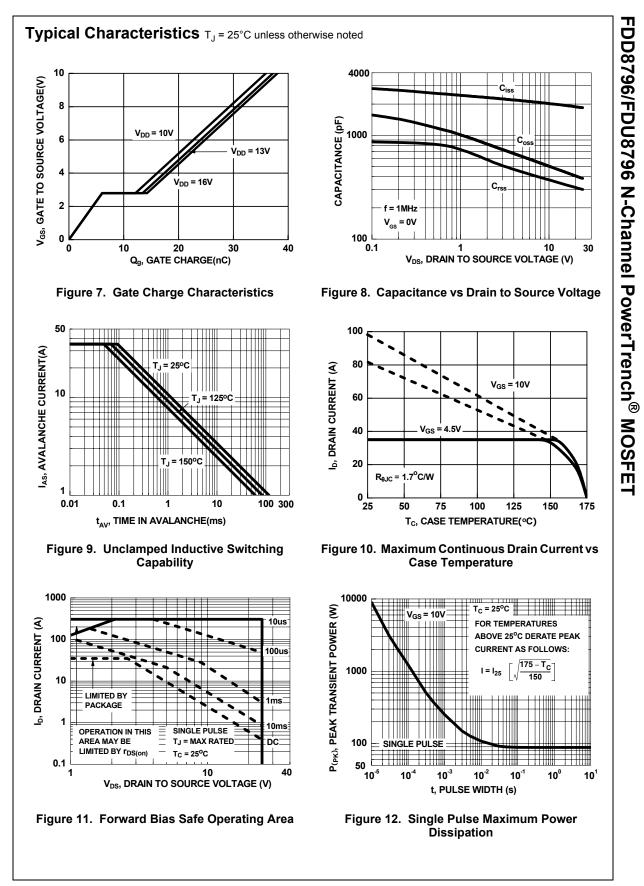
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Off Chara	cteristics						
B <sub>VDSS</sub>	Drain to Source Breakdown Voltage	I <sub>D</sub> = 250μA, V <sub>GS</sub> = 0V	25			V	
ΔB <sub>VDSS</sub> ΔT <sub>J</sub>	Breakdown Voltage Temperature Coefficient	$I_D = 250 \mu A$ , referenced to $25^{\circ}C$		7		mV/°C	
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = 20V$ $V_{GS} = 0V$ $T_{J} = 150^{\circ}C$			1 250	μA	
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = \pm 20V$			±100	nA	
On Chara	cteristics						
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	1.2	1.8	2.5	V	
$\Delta V_{GS(th)}$ $\Delta T_J$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \mu A$ , referenced to $25^{\circ}C$		-6.7		mV/°C	
·		V <sub>GS</sub> = 10V, I <sub>D</sub> = 35A		4.5	5.7		
r <sub>DS(on)</sub>	Drain to Source On Resistance	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 35A		6.0	8.0	mΩ	
		V <sub>DS</sub> = 10V, I <sub>D</sub> = 35A T <sub>J</sub> = 175°C		6.9	9.5	11122	
Dynamic	Characteristics						
C <sub>iss</sub>	Input Capacitance			1960	2610	pF	
C <sub>oss</sub>	Output Capacitance	— V <sub>DS</sub> = 13V, V <sub>GS</sub> = 0V, — f = 1MHz		455	605	pF	
C <sub>rss</sub>	Reverse Transfer Capacitance			315	475	pF	
R <sub>G</sub>	Gate Resistance	f = 1MHz		1.1		Ω	
Switching	g Characteristics						
t <sub>d(on)</sub>	Turn-On Delay Time			10	20	ns	
t <sub>r</sub>	Rise Time	V <sub>DD</sub> =13V, I <sub>D</sub> = 35A		24	39	ns	
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{GS} = 10V, R_{GS} = 20\Omega$		99	158	ns	
t <sub>f</sub>	Fall Time			57	91	ns	
Qg	Total Gate Charge	$V_{GS} = 0 \text{ to } 10V$ $V_{GS} = 0 \text{ to } 5V$ $V_{DD} = 13V,$ $I_{D} = 35A,$		37	52	nC	
Q <sub>g</sub>	Total Gate Charge	$V_{GS} = 0 \text{ to } 5V$ $V_{DD} = 13V,$		19	27	nC	
Q <sub>gs</sub>	Gate to Source Gate Charge	I <sub>D</sub> = 35A, I <sub>a</sub> = 1.0mA		6		nC	
Q <sub>gd</sub>	Gate to Drain Charge	ig itemation		6		nC	
Drain-Sou	urce Diode Characteristics	- · · · ·					
V <sub>SD</sub>	Source to Drain Diade Valtage	V <sub>GS</sub> = 0V, I <sub>S</sub> = 35A		0.9	1.25	V	
	Source to Drain Diode Voltage	V <sub>GS</sub> = 0V, I <sub>S</sub> = 15A		0.8	1.0	V	
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 35A, di/dt = 100A/μs		30	45	ns	
Q <sub>rr</sub>	Reverse Recovery Charge	I <sub>F</sub> = 35A, di/dt = 100A/μs		23	35	nC	

 $\label{eq:relation} \begin{array}{|c|c|c|} \hline $Q_{fT}$ & Reverse Recovery ordered \\ \hline $Notes:$ \\ 1: Pulse time < 300 \mu s, Duty cycle = 2%. \\ 2: Starting T_J = 25^\circ C, L = 0.3mH, I_{AS} = 24.7A, V_{DD} = 23V, V_{GS} = 10V. \\ \hline \end{tabular}$ 

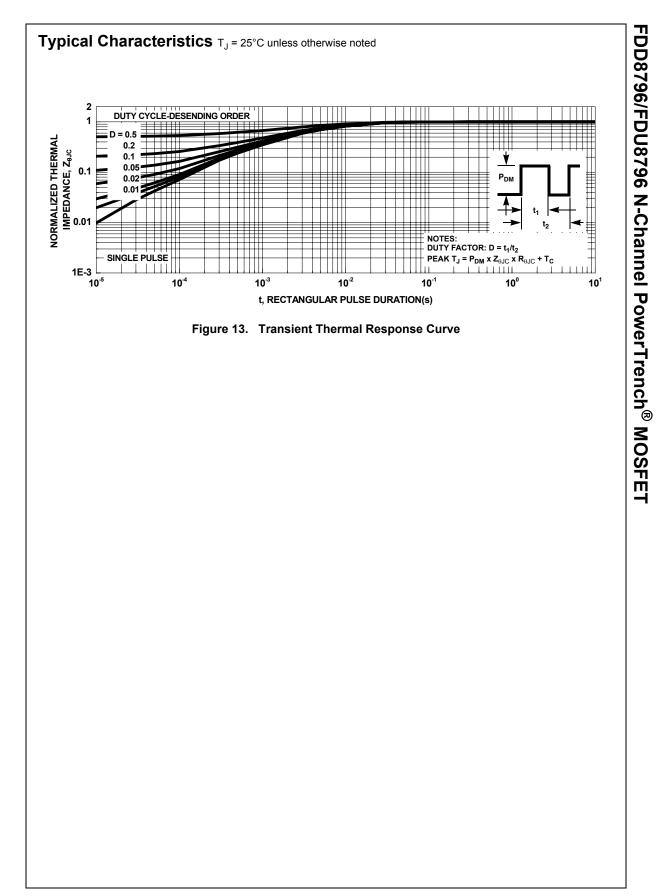


FDD8796/FDU8796 Rev. 1.1

www.fairchildsemi.com



FDD8796/FDU8796 Rev. 1.1





ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor has against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death ass

### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

© Semiconductor Components Industries, LLC